

June 2008

FPF2213-FPF2215 Integrated Load Switch with Adjustable High Precision Current Limit

FPF2213-FPF2215 Integrated Load Switch with Adjustable High Precision Current Limit

Features

- 1.8 to 5.5V Input Voltage Range
- Typical R_{DS(ON)} = 250mΩ @ V_{IN} = 5.5V
- Typical R_{DS(ON)} = 275mΩ @ V_{IN} = 3.3V
- 100-250mA (min) Adjustable Current Limit
- 5% Current Limit Tolerance @ 250mA (min)
- 72Ω (typ) Output Discharge Resistance
- ESD Protected, Above 8000V HBM and 2000V CDM

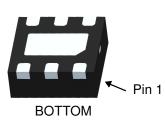
Applications

- PDAs
- Cell Phones
- GPS Devices
- MP3 Players
- Digital Cameras
- Peripheral Ports
- Notebook Computer

General Description

The FPF2213-FPF2215 are low $R_{DS(ON)}$ P-Channel MOSFET load switches with high precision current limit value. The input voltage range operates from 1.8V to 5.5V to fulfill today's Ultra Portable Device's supply requirement. Switch control is by a logic input (ON) capable of interfacing directly with low voltage control signal. On-chip pull-down is available for output quick discharge when switch is turned off.

For the FPF2214, if the constant current condition still persists after 30ms, these parts will shut off the switch and pull the fault signal pin (FLAGB) low. The FPF2213 has an auto-restart feature, which will turn the switch on again after 450mS if the ON pin is still active. The FPF2214 do not have this auto-restart feature so the switch will remain off until the ON pin is cycled. For the FPF2215, a current limit condition will immediately pull the fault signal pin low and the part will remain in the constant-current mode until the switch current falls below the current limit. For the FPF2213 through FPF2215, the current limit is set by an external resistor and the minimum current limit is 100mA.

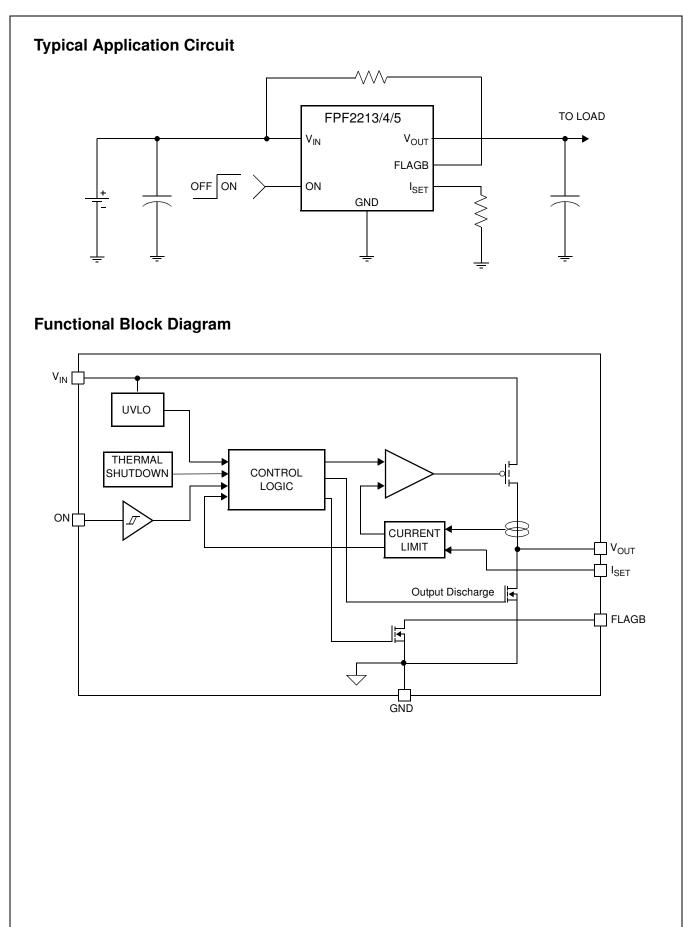




Ordering Information

Part	Current Limit (mA)	Current Limit Blanking Time (mS)	Auto-Restart Time (mS)	ON Pin Activity
FPF2213	100-250	30	450	Active HI
FPF2214	100-250	30	NA	Active HI
FPF2215	100-250	NA	NA	Active HI

1



Pin Configuration ON 6 1 IseT GND 5 2 VIN FLAGB 4 3 VOUT MicroFET 2x2 6L (BOTTOMVIEW)

Pin Description

Pin	Name	Function	
1	I _{SET}	Current Limit Set Input : A resistor from I _{SET} to ground sets the current limit for the switch	
2	V _{IN}	Supply Input: Input to the power switch and the supply voltage for the IC	
3	V _{OUT}	Switch Output: Output of the power switch	
4	FLAGB	Fault Output: Active LO, open drain output which indicates an over current, supply under voltage or over temperature state	
5	GND	Ground	
6	ON	ON/OFF Control Input	

Absolute Maximum Ratings

Parameter	Min.	Max.	Unit	
V _{IN} , V _{OUT} , ON, FLAGB TO GND		-0.3	6	V
I _{SET} TO GND		-0.3	0.3	V
Power Dissipation @ T _A = 25 ℃		1.2	W	
Operating and Storage Junction Temperature	-65	125	°C	
Thermal Resistance, Junction to Ambient			86	℃/W
Electrostatic Discharge Protection HBM		8000		V
	MM	400		V
	CDM	2000		V

Recommended Operating Range

Parameter	Min.	Max.	Unit
V _{IN}	1.8	5.5	V
Ambient Operating Temperature, T _A	-40	85	ç

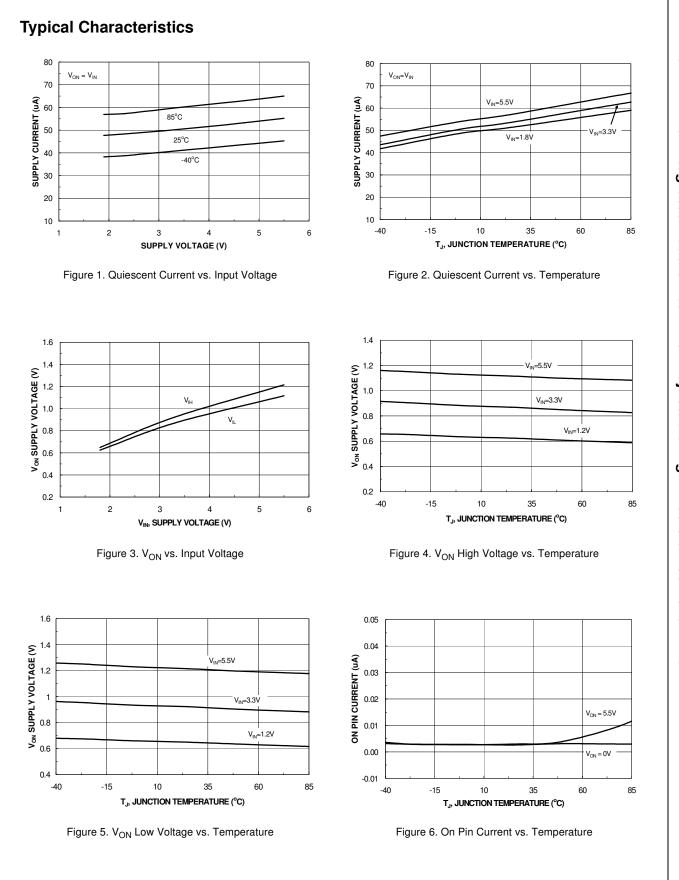
Electrical Characteristics

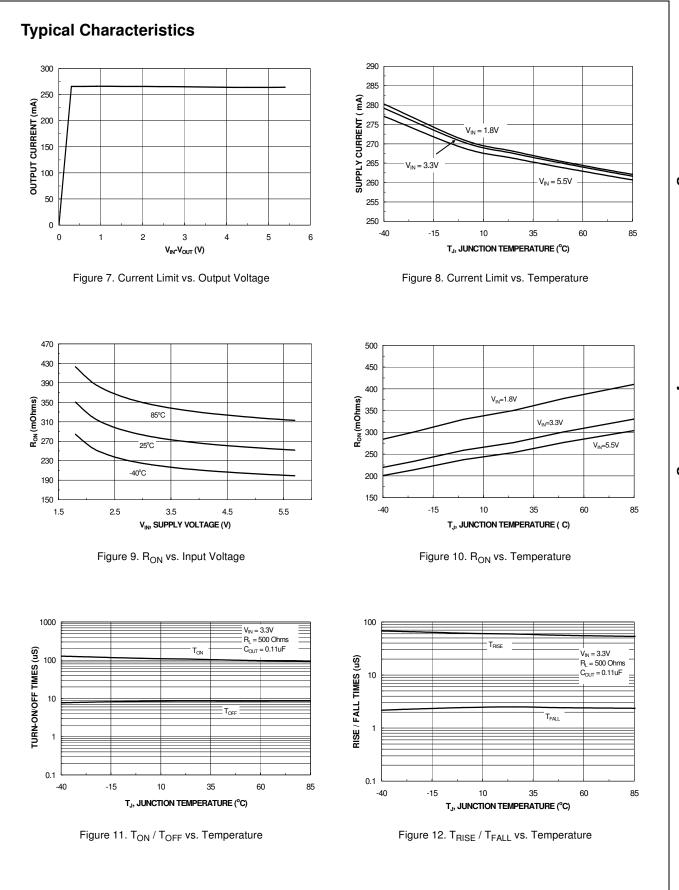
 V_{IN} = 1.8 to 5.5V, T_A = -40 to +85 °C unless otherwise noted. Typical values are at V_{IN} = 3.3V and T_A = 25 °C.

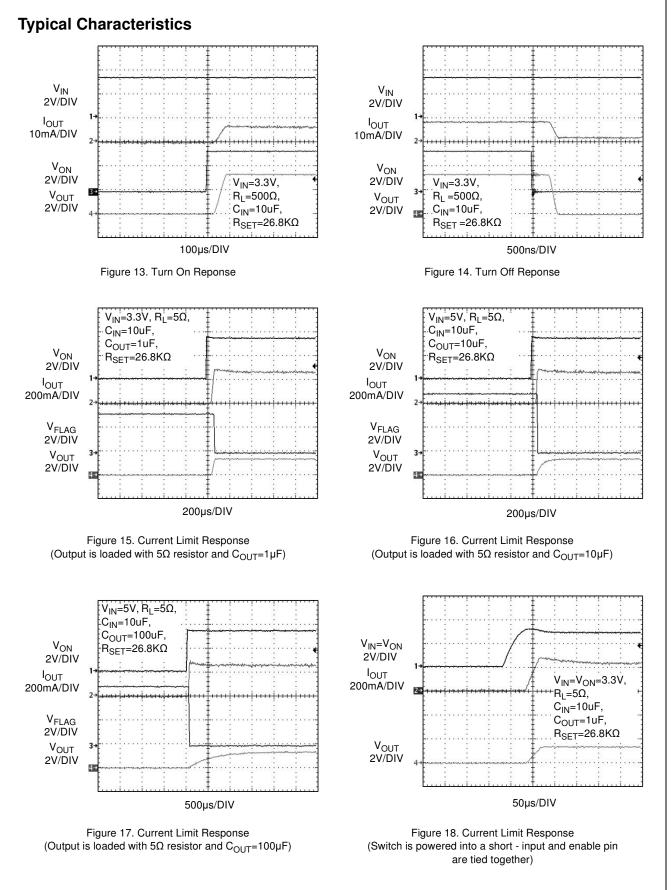
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Basic Operation	·					
Operating Voltage	V _{IN}		1.8		5.5	V
		I_{OUT} =0mA, V_{IN} = V_{ON} =1.8V, R_{SET} =26.8K		45	75	
Quiescent Current	Ι _Q	I_{OUT} =0mA, V_{IN} = V_{ON} =3.3V, R_{SET} =26.8K		50	85	μA
		I_{OUT} =0mA, V_{IN} = V_{ON} =5.5V, R_{SET} =26.8K		60	95	
VIN Shutdown Current		V_{ON} =0V, V_{IN} =5.5V, V_{OUT} =short to GND			2.5	μA

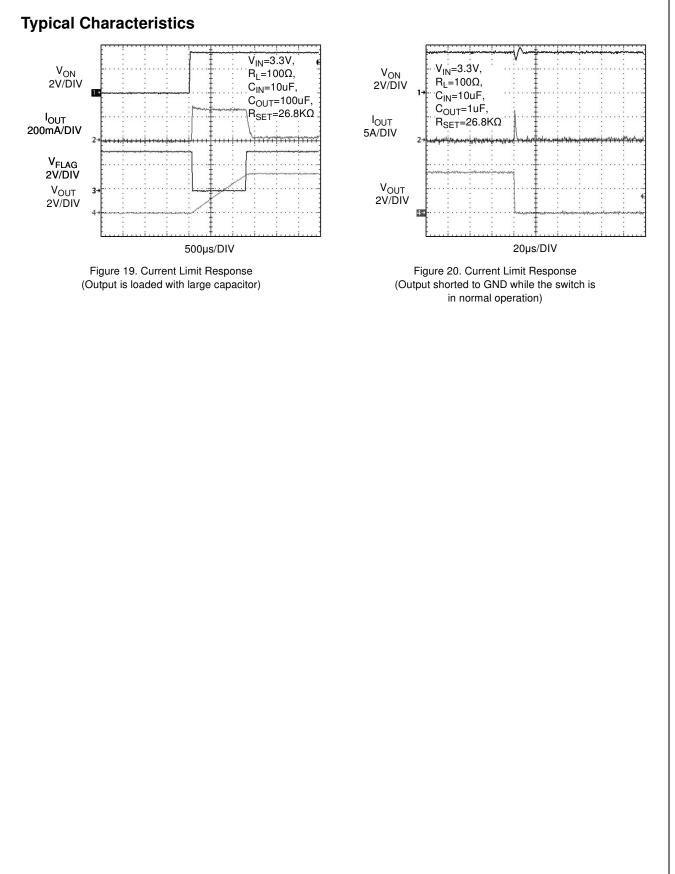
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units	
V _{OUT} Shutdown Current		V _{ON} =0V, V _{OUT} =5.5V, V _{IN} =short to GND			1	μA	
		V _{IN} =5.5V, I _{OUT} =200mA, T _A =25℃		250	325		
		V _{IN} =3.3V, I _{OUT} =200mA, T _A =25℃		275	360		
On-Resistance	R _{ON}	V _{IN} =1.8V, I _{OUT} =200mA, T _A =25℃		350	455	455 mΩ	
		V_{IN} =3.3V, I_{OUT} =200mA, T _A =-40 to +80 °C			450		
Output Discharge Resistance		V _{IN} =3.3V, V _{ON} =0V, I _{OUT} =10mA		72	105	Ω	
ON Input Logia High Voltage (ON)	V	V _{IN} =1.8V	0.8				
ON Input Logic High Voltage (ON)	V _{IH}	V _{IN} =5.5V	1.4			V	
ON Input Logic Low Voltage (OFF)	V	V _{IN} =1.8V	0.5		v		
ON Input Logic Low Voltage (OFF)	V _{IL}	V _{IN} =5.5V			1.0	v	
On Input Leakage		V _{ON} = V _{IN} or GND	-1		1	μA	
		V _{IN} =5.5V, I _{SINK} =100µA		0.05	0.1 V		
FLAGB Output Logic Low Voltage		V _{IN} =1.8V, I _{SINK} =100µA		0.12	0.25	v	
FLAGB Output High Leakage Current		V _{IN} =5.5V, Switch on			1	μA	
Protections Current Limit	I _{LIM}	V _{IN} =3.3V, V _{OUT} = 3.0V, R _{SET} =26.8K, T _A =25 °C	250	263	276	mA	
		Shutdown Threshold		140			
Thermal Shutdown		Return from Shutdown		130		°C	
		Hysteresis		100		Ŭ	
Under Voltage Shutdown	UVLO	V _{IN} increasing	1.55	1.65	1.75	V	
Under Voltage Shutdown Hysteresis				50		mV	
Dynamic					l		
Turn On Time	t _{ON}	$R_L=500\Omega, C_L=0.001 uF$		70		μS	
Turn Off Time	t _{OFF}	R _L =500Ω, C _L =0.001uF		600		nS	
V _{OUT} Rise Time	t _{RISE}	R _L =500Ω, C _L =0.001uF		40		μS	
V _{OUT} Fall Time	t _{FALL}	R _L =500Ω, C _L =0.001uF		100		nS	
Over Current Blanking Time	t _{BLANK}	FPF2213, FPF2214	15	30	60	mS	
Auto-Restart Time	t _{RSTRT}	FPF2213	225	450	900	mS	
Current Limit Response Time		$\label{eq:VIN} \begin{array}{l} V_{IN} = V_{ON} = 3.3V. \ Over-Current\\ Condition: R_{LOAD} = V_{IN}/(I_{LIM}x4) \end{array}$		5		μS	

4









Description of Operation

The FPF2213, FPF2214, and FPF2215 are state of the art Adjustable High Precision Current Limit switches that protect systems and loads which can be damaged or disrupted by the application of high currents. The core of each device is a 0.27Ω P-channel MOSFET and a controller capable of functioning over an input operating range of 1.8V - 5.5V. The controller protects offers current limiting, UVLO(undervoltage lockout) and thermal shutdown protection. The current limit is adjustable from 100mA to 250mA through the selection of an external resistor.

On/Off Control

The ON pin is active high, and controls the state of the switch. Applying a continuous high signal will hold the switch in the on state. The switch will move into the OFF state when the active high is removed, or if a fault is encountered. For all versions, an undervoltage on VIN or a junction temperature in excess of 140 °C overrides the ON control to turn off the switch.

In addition, excessive currents will cause the switch to turn off in the FPF2213 and FPF2214. The FPF2213 has an Auto-Restart feature which will automatically turn the switch on again after 450ms. For the FPF2214, the ON pin must be toggled to turn-on the switch again. The FPF2215 does not turn off in response to an over current condition but instead remains operating in a constant current mode so long as ON is active and the thermal shutdown or UVLO have not activated.

Fault Reporting

Upon the detection of an over-current condition, an input UVLO, or an over-temperature condition, the FLAGB signals the fault mode by activating LO. In the event of an over-current condition for the FPF2213 and FPF2214, the FLAGB goes LO at the end of the blanking time while FLAGB goes LO immediately for the FPF2215. If the over-current condition lasts longer than blanking time, FLAGB remains LO through the Auto-Restart Time for the FPF2213 while for the FPF2214, FLAGB is latched LO and ON must be toggled to release it. With the FPF2215, FLAGB is LO during the faults and immediately returns HI at the end of the fault condition. FLAGB is an open-drain MOSFET which requires a pull-up resistor between VIN and FLAGB. During shutdown, the pull-down on FLAGB is disabled to reduce current draw from the supply. A 100K Ω pull up resistor is recommended to be used in the application.

Current Limiting

The current limit ensures that the current through the switch doesn't exceed a maximum value while not limiting at less than a minimum value. The current at which the parts will limit is adjustable through the selection of an external resistor connected to the ISET pin. Information for selecting the resistor is found in the Application Information section of this datasheet. The FPF2213 and FPF2214 have a blanking time of 30ms (nominal) during which the switch will act as a constant current source. At the end of the blanking time, the switch will be turned-off. The FPF2215 has no current limit blanking period so it will remain in a constant current state until the ON pin is deactivated or the thermal shutdown turns-off the switch.

Undervoltage Lockout (UVLO)

The undervoltage lockout turns-off the switch if the input voltage drops below the undervoltage lockout threshold. With the ON pin active the input voltage rising above the undervoltage lockout threshold will cause a controlled turn-on of the switch which limits current over-shoots.

Output Discharge Resistor

The FPF2213/4/5 family contains an 80 Ω on-chip load resistor for quick output discharge when the switch is turned off. This features become more attractive when application requires large output capacitor to be discharge when the switch turns off. However, V_{OUT} pin should not be connected directly to the battery source due to the discharge mechanism of the load switch.

Thermal Shutdown

The thermal shutdown protects the die from internally or externally generated excessive temperatures. During an overtemperature condition the FLAGB is activated and the switch is turned-off. The switch automatically turns-on again if temperature of the die drops below the threshold temperature.

Application Information

Setting Current Limit

The FPF2213, FPF2214, and FPF2215 have adjustable high precision current limit which is set with an external resistor connected between ISET and GND. Please see the layout recommendation section of the application note for the recommended R_{SET} layout. The R_{SET} resistance is selected by using the following equation:

$$I_{\text{LIM (Typ)}} (\text{mA}) = \frac{7050}{\text{R}_{\text{SET}} (\text{K}\Omega)}$$

For a particular $I_{\text{LIM}}(\text{min})$ value, R_{SET} can be calculated from below formula:

$$R_{SET}(K\Omega) = \frac{7050}{I_{LIM (Min)} (mA) + 10 + \frac{750}{I_{LIM (Min)} (mA)}}$$

FPF221X family has 5% precision at higher load current. The I_{LIM (Max)} and tolerance of current limit value can be determined using Figure 21 (I_{LIM} vs R_{SET}) and the following formula:

Tolerance (%) = 100 *
$$\frac{I_{LIM (Typ)} - I_{LIM (Min)}}{I_{LIM (Typ)}}$$

$$I_{\text{LIM (Max)}} = I_{\text{LIM (Typ)}} + \frac{I_{\text{LIM (Typ)}} * \text{Tolerance (\%)}}{100}$$

The table and figure below can be used to select R_{SET}:

R _{SET} [kΩ]	Min. Current Limit [mA]	Typ. Current Limit [mA]	Max. Current Limit [mA]	Tol [%]
26.8	250	263	276	5.0
28.0	238	252	265	5.4
29.4	226	240	253	5.7
30.0	221	235	249	5.8
32.4	204	218	232	6.4
36.5	179	193	208	7.5
40.2	160	175	190	8.5
48.7	129	145	161	11.1
60.0	100	118	135	15.0

Table 1: R_{SET} Selection Guide

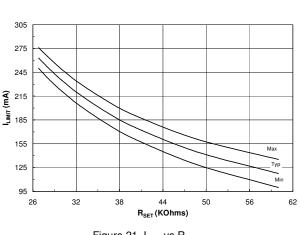


Figure 21. ILIM vs RSET

Input Capacitor

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch is turned on into a discharged load capacitor or a short-circuit, a capacitor is recommended to be placed between V_{IN} and GND. A 1uF ceramic capacitor, C_{IN}, placed close to the pins is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop.

Output Capacitor

A 0.1uF capacitor C_{OUT} , should be placed between V_{OUT} and GND. This capacitor will prevent parasitic board inductances from forcing V_{OUT} below GND when the switch turns-off. For the FPF2213 and FPF2214, the total output capacitance needs to be kept below a maximum value, $C_{OUT}(max)$, to prevent the part from registering an over-current condition and turning-off the switch. The maximum output capacitance can be determined from the following formula:

$$C_{OUT (Max)} = \frac{I_{LIM (Max)} * t_{BLANK (Min)}}{V_{IN}}$$

Power Dissipation

During normal on-state operation, the power dissipated in the device will depend upon the level at which the current limit is set. The maximum allowed setting for the current limit is 250mA and will result in a power dissipation of:

$$P = (I_{LIM})^2 * R_{DS} = (0.25)^2 * 0.275 = 17mW$$

If the part goes into current limit, maximum power dissipation will occur when the output is shorted to ground. For the FPF2213, the power dissipation will be scaled by the Auto-Restart Time, t_{RSTRT}, and the Over Current Blanking Time, t_{BLANK}. Therefore, the maximum power dissipated is:

$$P_{(Max)} = \frac{t_{BLANK}}{t_{BLANK} + t_{RSTRT}} * V_{IN (Max)} * I_{LIM (Max)}$$
$$= \frac{30}{30 + 450} * 5.5 * 0.276 = 94 \text{mW}$$

Take note that this is below the maximum package power dissipation, and the thermal shutdown feature will act as additional safety to protect the part from damage due to excessive heating. The junction temperature is only able to increase to the thermal shutdown threshold. Once this temperature has been reached, toggling ON will not turn-on the switch until the junction temperature drops. For the FPF2215, a short on the output will cause the part to operate in a constant current state dissipating a worst case power of:

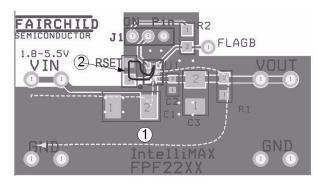
 $P_{(Max)} = V_{IN (MAX)} * I_{LIM (MAX)} = 5.5 * 0.276 = 1.5W$

This large amount of power will activate the thermal shutdown and the part will cycle in and out of thermal shutdown so long as the ON pin is active and the short is present.

PCB Layout Recommendations

In order to benefit from adjustable, high-precision load switch devices, a high-precision $\mathsf{R}_{\mathsf{SET}}$ value must be used to set a tight current limit tolerance. Since $\mathsf{I}_{\mathsf{LIMIT}}$ (current limit value) is determined by the voltage drop across the $\mathsf{R}_{\mathsf{SET}}$, a poor PCB layout can introduce parasitic noise on the $\mathsf{I}_{\mathsf{SET}}$ pin resulting in a minor variation of $\mathsf{I}_{\mathsf{LIMIT}}$. To improve the $\mathsf{I}_{\mathsf{LIMIT}}$ stability, parasitic noise coupling mechanisms from $\mathsf{I}_{\mathsf{SET}}$ to GND must be minimized. This becomes more critical when $\mathsf{I}_{\mathsf{LIMIT}}$ is set close to the nominal load current operation where parasitic effects could cause the device to go in and out of current limit and result in an error flag report.

Care must be taken to provide a direct current return path between the R_{SET} ground pad and the device ground pad (pin5). Please see current pad #2 in figure below.



1)Power current path

2)RSET current path

Figure 22: Eliminate parasitic noise of ISET-GND by providing a separate ground route, unique from the power ground plane

Improving Thermal Performance

An improper layout could result in higher junction temperature and triggering the thermal shutdown protection feature. This concern applies when the switch is set at higher current limit value and an over-current condition occurs. In this case, the power dissipation of the switch, from the formula below, could exceed the maximum absolute power dissipation of 1.2W.

 $PD = (V_{IN} - V_{OUT}) \times I_{LIM (Max)}$

The following techniques have been identified to improve the thermal performance of this family of devices. These techniques are listed in order of the significance of their impact.

1. Thermal performance of the load switch can be improved by connecting pin7 of the DAP (Die Attach Pad) to the GND plane of the PCB.

2. Embedding two exposed through-hole vias into the DAP (pin7) provides a path for heat to transfer to the back GND plane of the PCB. A drill size of Round, 14 mils (0.35mm) with 1-ounce copper plating is recommended to result in appropriate solder reflow. A smaller size hole prevents the solder from penetrating into the via, resulting in device lift-up. Similarly, a larger via-hole consumes excessive solder, and may result in voiding of the DAP.

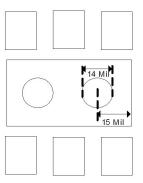


Figure 23: Two through hole open vias embedded in DAP

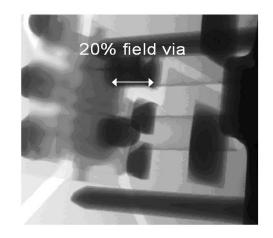


Figure 24: X-Ray result (bottom view with 45° angle)

3. The V_{IN}, V_{OUT} and GND pins will dissipate most of the heat generated during a high load current condition. Using wide traces will help minimize parasitic electrical effects along with minimizing the case to ambient thermal impedance. The layout suggested in Figure 25 provides each pin with adequate copper so that heat may be transferred as efficiently as possible out of the device. The low-power FLAGB and ON pin traces may be laid-out diagonally from the device to maximize the area available to the ground pad. Placing the input and output capacitors as close to the device as possible also contributes to heat dissipation, particularly during high load currents.

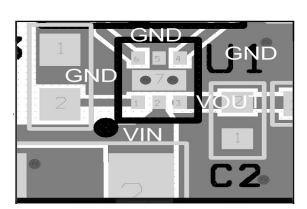


Figure 25: Proper layout of output and ground copper area

FPF22XX Demo Board

FPF22XX Demo board has components and circuitry to demonstrate FPF2213/4/5 load switches functions and features. R4 resistor with 0 Ω value is used for measuring the output current. Load current can be scoped by removing the R4 resistor and soldering a current loop to the R4 footprint. Thermal performance of the board is improved using a few techniques recommended in the layout recommendations section of datasheet.

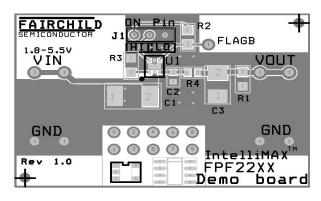


Figure 26: Top, SST, and AST Layers

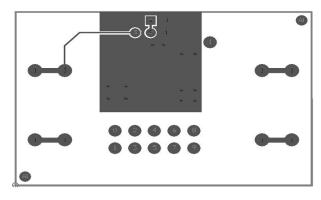


Figure 27: Bottom and ASB Layers

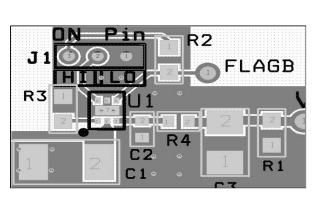
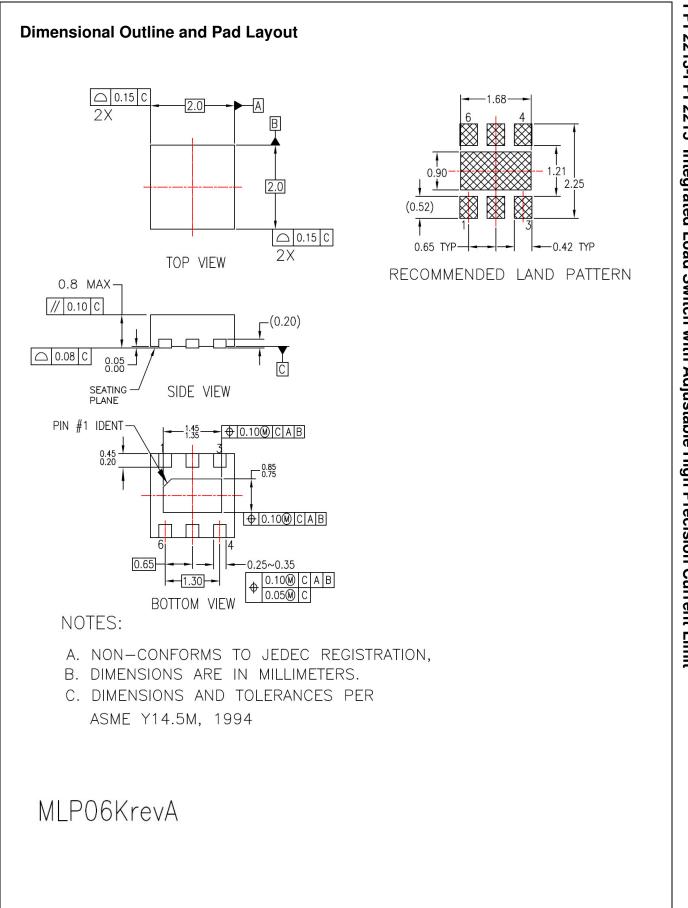


Figure 28: Zoom in to Top layer



FAIRCHILD

SEMICONDUCTOR

TRADEMARKS

The following are registered and unregistered trademarks and service marks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx[®] FPS™ PDP-SPM™ FRFET[®] Power220[®] Build it Now™ POWEREDGE[®] CorePLUS™ Global Power ResourceSM *CROSSVOLT*™ Green FPS™ Power-SPM™ Green FPS™ e-Series™ CTI ™ PowerTrench[®] GTO™ Programmable Active Droop™ Current Transfer Logic™ QFET[®] EcoSPARK[®] i-Lo™ QS™ EZSWITCH™ * IntelliMAX™ **ISOPLANAR™** QT Optoelectronics™ MegaBuck™ Quiet Series™ MICROCOUPLER™ RapidConfigure™ Fairchild[®] SMART START™ MicroFET™ SPM[®] Fairchild Semiconductor® MicroPak™ FACT Quiet Series™ MillerDrive™ STEALTH™ FACT[®] Motion-SPM[™] SuperFET™ FAST® OPTOLOGIC[®] SuperSOT™-3 **OPTOPLANAR[®]** FastvCore™ SuperSOT™-6 FlashWriter[®] * SuperSOT™-8

SyncFET™ GENERAL The Power Franchise[®] pure franchise

SupreMOS™

TinyBoost™ TinyBuck™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ µSerDes™ UHC® Ultra FRFET™ UniFET™ VCX™

* EZSWITCHTM and FlashWriter[®] are trademarks of System General Corporation, used under license by Fairchild Semiconducntor.

DISCLAIMER

⊢7

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support 2 device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification Product Status		Definition		
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.		

Rev. 133